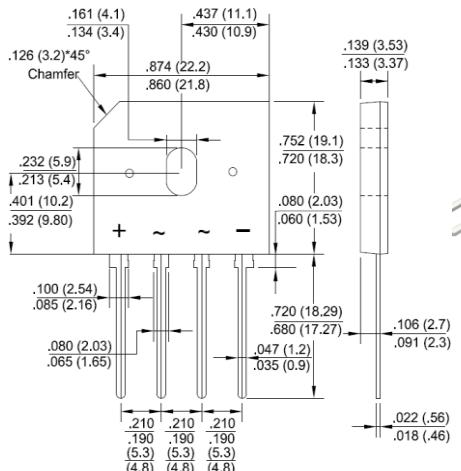


GBU4005 THRU GBU410

Glass Passivated Bridge Rectifiers	Reverse Voltage - 50 to 1000 Volts Forward Current - 4.0 Amperes
<p>Features</p> <ul style="list-style-type: none"> • Glass passivated chip • Low forward voltage drop • Ideal for printed circuit board • High surge current capability <p>Mechanical Data</p> <ul style="list-style-type: none"> • Polarity: Symbol marked on body • Mounting position: Any <p>Applications</p> <ul style="list-style-type: none"> • General purpose use in AC/DC bridge full wave rectification, for SMPS, lighting ballaster, adapter, etc. 	 <p>GBU</p>  <p>Package Outline Dimensions in Inches (Millimeters)</p>

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristics	Symbol	GBU4005	GBU401	GBU402	GBU404	GBU406	GBU408	GBU410	Unit
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _D C	50	100	200	400	600	800	1000	V
Maximum Average Forward (with heatsink Note 2)	I _(AV)								A
Rectified Current @ T _C =100°C (without heatsink)									
Peak Forward Surge Current, 8.3mS Single Half Sine-Wave, Superimposed on Rated Load (JEDEC Method)	I _{FSM}								A
I ² t Rating for Fusing (t<8.3mS)	I ² t								A ² s
Peak Forward Voltage Per Diode at 2A DC	V _F								V
Peak Forward Voltage per Diode at 4A DC	V _F								V
Maximum DC Reverse Current at Rated @ T _J =25°C	I _R								μA
DC Blocking Voltage per Diode @ T _J =125°C									
Typical Junction Capacitance Per Diode (Note1)	C _J								pF
Typical Thermal Resistance to Ambient (without heatsink)	R _{θJA}								°C/W
Typical Thermal Resistance to case (with heatsink (Note2))	R _{θJC}								°C/W
Typical Thermal Resistance to lead (without heatsink)	R _{θJL}								°C/W
Operating Junction Temperature Range	T _J								°C
Storage Temperature Range	T _{STG}								°C

Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

2. Device mounted on 50mm*50mm*1.6mm Cu plate heatsink.

3. The typical data above is for reference only

Rating and Characteristic Curves

GBU4005 THRU GBU410

Fig. 1 - Forward Current Derating Curve

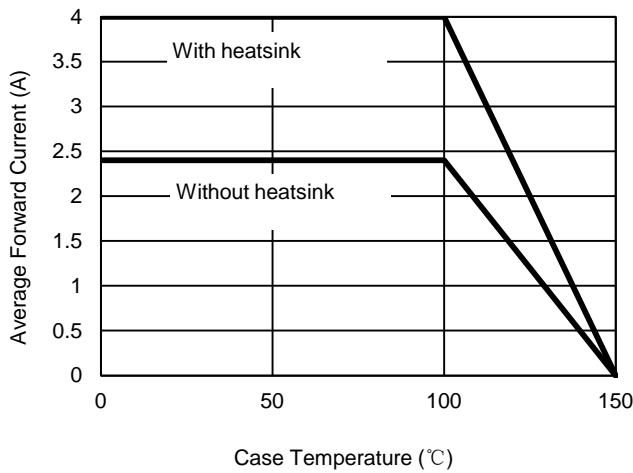


Fig. 2 - Maximum Non-Repetitive Surge Current

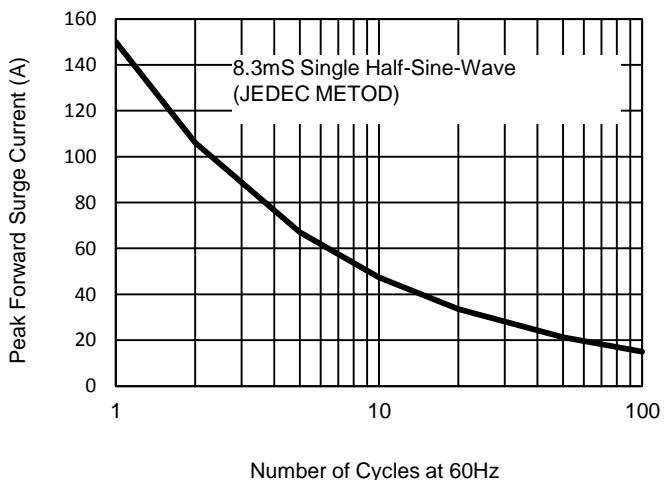


Fig. 3 - Typical Reverse Characteristics

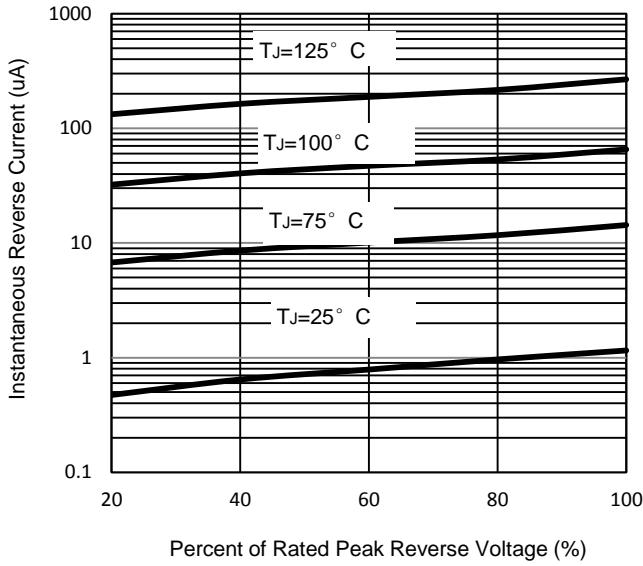


Fig. 4 - Typical Forward Characteristics

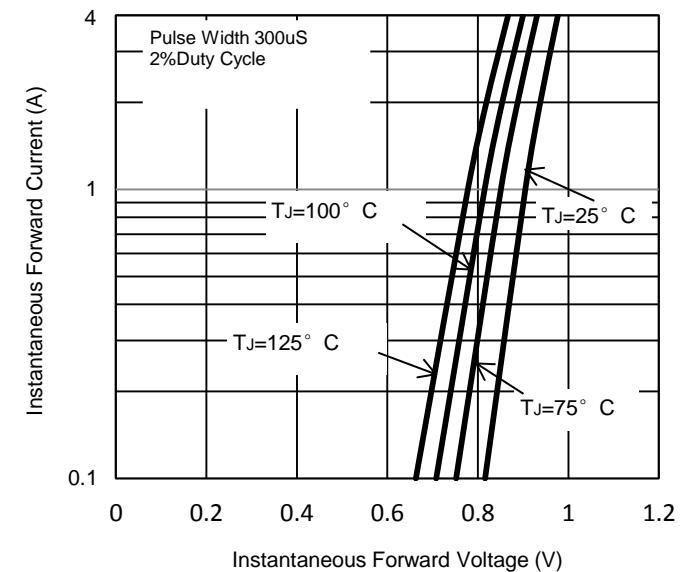
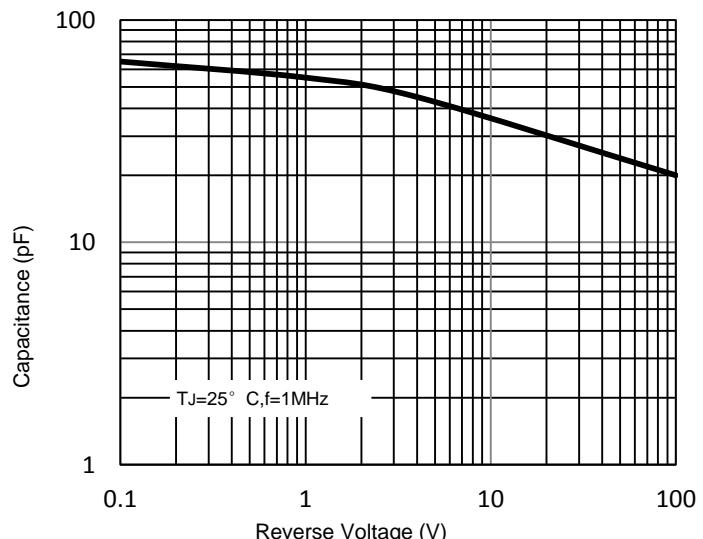


Fig. 5 - Typical Junction Capacitance



The curve above is for reference only.

